Switching Transistor

NPN Silicon

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	40	Vdc
Collector-Base Voltage	V _{CBO}	60	Vdc
Emitter-Base Voltage	V_{EBO}	6.0	Vdc
Collector Current – Continuous	۱ _C	600	mAdc
Collector Current – Peak	I _{CM}	900	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 1) @T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate (Note 2) @T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

*Transient pulses must not cause the junction temperature to be exceeded.

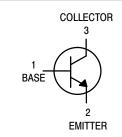
1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



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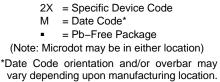
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MARKING DIAGRAM





ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT4401LT1G SMMBT4401LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBT4401LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS	•				
Collector – Emitter Breakdown Voltage (Note 3) $(I_{C} = 1.0 \text{ mAdc}, I_{B} = 0)$		V _{(BR)CEO}	40	-	Vdc
Collector-Base Breakdown Voltage	(I _C = 0.1 mAdc, I _E = 0)	V _{(BR)CBO}	60	-	Vdc
Emitter-Base Breakdown Voltage	(I _E = 0.1 mAdc, I _C = 0)	V _{(BR)EBO}	6.0	-	Vdc
Base Cutoff Current	(V _{CE} = 35 Vdc, V _{EB} = 0.4 Vdc)	I _{BEV}	-	0.1	μAdc
Collector Cutoff Current	(V _{CE} = 35 Vdc, V _{EB} = 0.4 Vdc)	ICEX	-	0.1	μAdc
ON CHARACTERISTICS (Note 3)					
$\label{eq:current Gain} \begin{array}{l} (I_C = 0.1 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \\ (I_C = 1.0 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \\ (I_C = 10 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \\ (I_C = 150 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) \\ (I_C = 500 \text{ mAdc}, V_{CE} = 2.0 \text{ Vdc}) \end{array}$		hFE	20 40 80 100 40	- - 300 -	-
Collector – Emitter Saturation Voltage $(I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc})$ $(I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$		V _{CE(sat)}		0.4 0.75	Vdc
Base – Emitter Saturation Voltage $(I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc})$ $(I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$		V _{BE(sat)}	0.75 -	0.95 1.2	Vdc
SMALL-SIGNAL CHARACTERISTI	cs				
Current-Gain - Bandwidth Product	$(I_{C} = 20 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 100 \text{ MHz})$	f _T	250	-	MHz
Collector–Base Capacitance	$(V_{CB} = 5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C _{cb}	-	6.5	pF
Emitter–Base Capacitance $(V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz})$		C _{eb}	-	30	pF
Input Impedance $(I_{C} = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$		h _{ie}	1.0	15	kΩ
Voltage Feedback Ratio $(I_{C} = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$		h _{re}	0.1	8.0	X 10 ⁻⁴
Small-Signal Current Gain	gnal Current Gain $(I_{C} = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$		40	500	-
Output Admittance $(I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$		h _{oe}	1.0	30	μmhos
SWITCHING CHARACTERISTICS					
Delay Time	(V _{CC} = 30 Vdc, V _{EB} = 2.0 Vdc,	t _d	-	15	ns
Rise Time	$I_{\rm C} = 150 \text{ mAdc}, I_{\rm B1} = 15 \text{ mAdc})$	t _r	-	20	113
Storage Time	(V _{CC} = 30 Vdc, I _C = 150 mAdc,	t _s	-	225	ns
Fall Time	$I_{B1} = I_{B2} = 15 \text{ mAdc}$	t _f	-	30	110

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

SWITCHING TIME EQUIVALENT TEST CIRCUITS

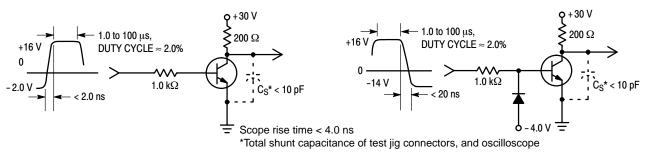


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

TRANSIENT CHARACTERISTICS

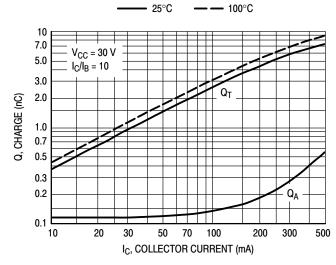
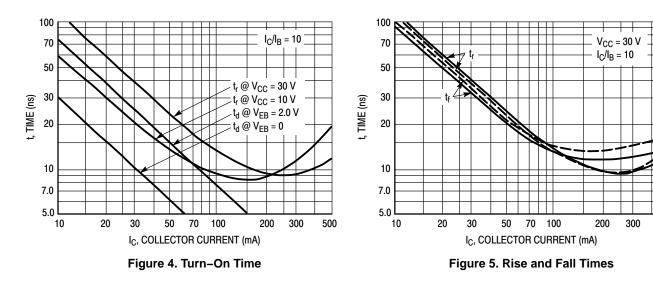
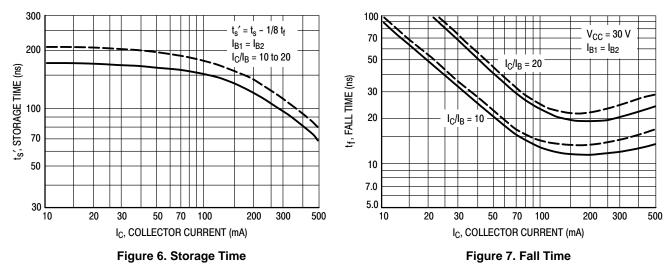
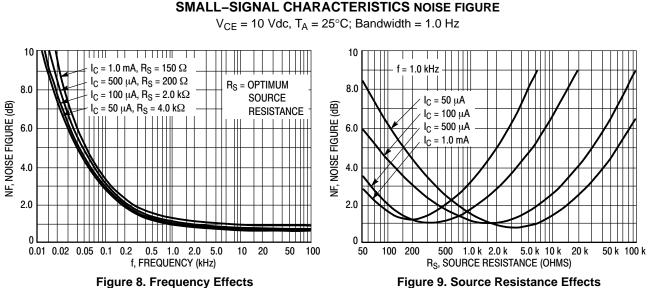


Figure 3. Charge Data



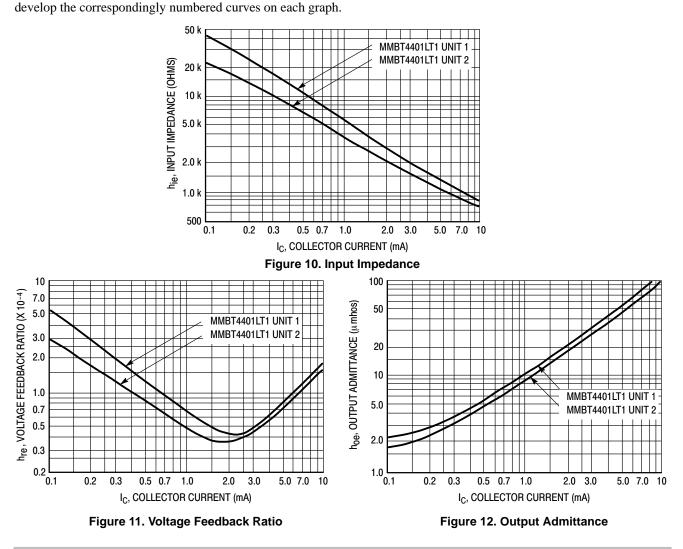
500





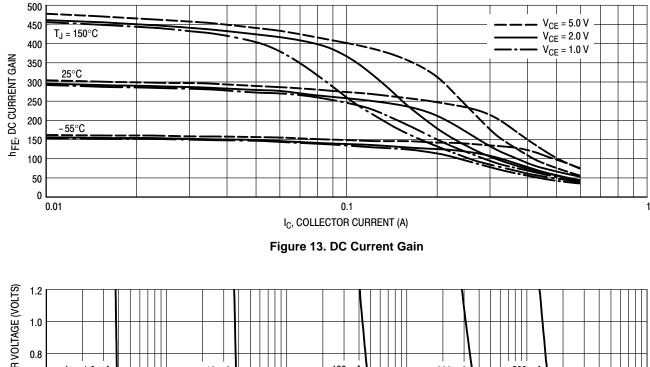
h PARAMETERS V_{CE} = 10 Vdc, f = 1.0 kHz, T_A = 25°C

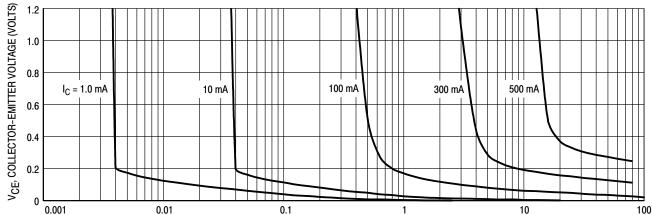
This group of graphs illustrates the relationship between h_{fe} and other "h" parameters for this series of transistors. To obtain these curves, a high–gain and a low–gain unit were selected from the MMBT4401LT1 lines, and the same units were used to



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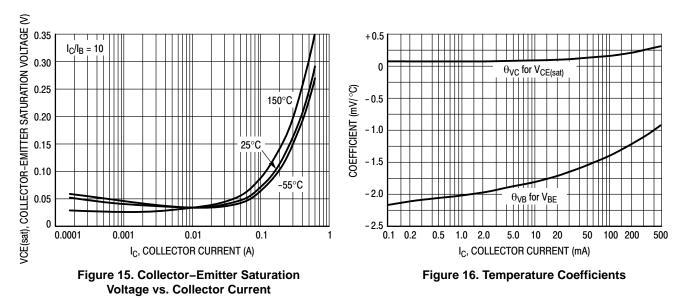




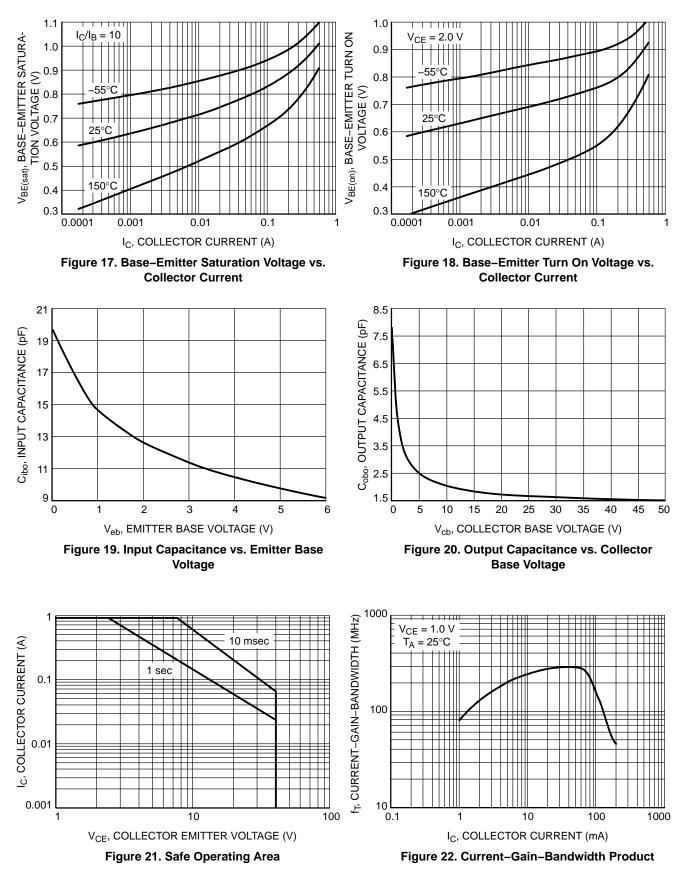








STATIC CHARACTERISTICS







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